





### NPN PRE-BIASED 500 mA SURFACE MOUNT TRANSISTOR

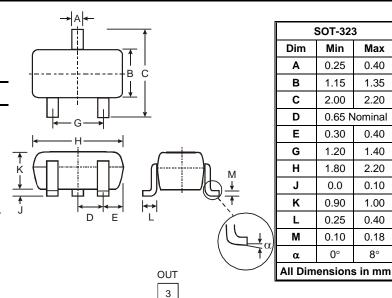
#### **Features**

- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDTB)
- Built-In Biasing Resistors
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device, Note 3 and 4

#### **Mechanical Data**

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking Information: See Table Below & Page 3
- Ordering Information: See Page 3
- Weight: 0.006 grams (approximate)

P/N	R1 (NOM)	R2 (NOM)	MARKING
DDTD122LU	0.22KΩ	10ΚΩ	N75
DDTD142JU	$0.47$ K $\Omega$	10KΩ	N76
DDTD122TU	$0.22$ K $\Omega$	OPEN	N77
DDTD142TU	$0.47$ K $\Omega$	OPEN	N78



1 2 IN GND(0)

R2

Schematic and Pin Configuration

#### **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Supply Voltage, (3) to (2)		V <sub>CC</sub>	50	٧
Input Voltage, (1) to (2)	DDTD122LU DDTD142JU	V <sub>IN</sub>	-5 to +6 -5 to +6	V
Input Voltage, (2) to (1)	DDTD122TU DDTD142TU	V <sub>EBO</sub> (MAX)	5	V
Output Current	All	Ic	500	mA
Power Dissipation	(Note 1)	P <sub>d</sub>	200	mW
Thermal Resistance, Junction to Ambient Air	(Note 1)	$R_{ hetaJA}$	625	°C/W
Operating and Storage Temperature Range		T <sub>j</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes:

- 1. Mounted on FR4 PC Board with recommended pad layout at http://www.diodes.com/datasheets/ap02001.pdf.
- 2. No purposefully added lead.
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.
- Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



## Electrical Characteristics @TA = 25°C unless otherwise specified R1, R2 Types

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Input Voltage	DDTD122LU DDTD142JU	V <sub>I(off)</sub>	0.3 0.3	_		V	V <sub>CC</sub> = 5V, I <sub>O</sub> = 100μA
	DDTD122LU DDTD142JU	V <sub>I(on)</sub>		_	2.0 2.0		$V_O = 0.3V$ , $I_O = 20mA$ $V_O = 0.3V$ , $I_O = 20mA$
Output Voltage		V <sub>O(on)</sub>		_	0.3V	V	$I_O/I_I = 50 \text{mA}/2.5 \text{mA}$
Input Current DDTD122LU DDTD142JU		lı		_	28 13	mA	V <sub>I</sub> = 5V
Output Current		I <sub>O(off)</sub>		_	0.5	μА	$V_{CC} = 50V, V_I = 0V$
DC Current Gain	DDTD122LU DDTD142JU	Gı	56 56	_			V <sub>O</sub> = 5V, I <sub>O</sub> = 50mA
Gain-Bandwidth Product*		f <sub>T</sub>	1	200		MHz	$V_{CE} = 10V, I_{E} = 5mA, f = 100MHz$

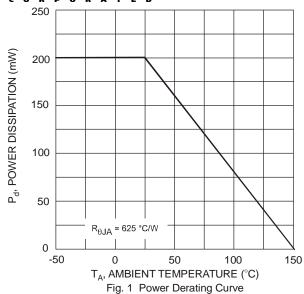
<sup>\*</sup> Transistor - For Reference Only

## Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified R1-Only, R2-Only Types

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	50	_	_	V	$I_C = 50\mu A$	
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	40	_	_	V	I <sub>C</sub> = 1mA	
Emitter-Base Breakdown Voltage DDTD122TU DDTD142TU		BV <sub>EBO</sub>	5			V	$I_E = 50\mu A$ $I_E = 50\mu A$
Collector Cutoff Current		I <sub>CBO</sub>	_		0.5	μА	V <sub>CB</sub> = 50V
Emitter Cutoff Current DDTD122TU DDTD142TU		I <sub>EBO</sub>	_		0.5 0.5	μА	V <sub>EB</sub> = 4V
Collector-Emitter Saturation Voltage		V <sub>CE(sat)</sub>	_		0.3	٧	I <sub>C</sub> = 50mA, I <sub>B</sub> = 2.5mA
DC Current Transfer Ratio DDTD122TU DDTD142TU		h <sub>FE</sub>	100 100	250 250	600 600	_	$I_C = 5mA$ , $V_{CE} = 5V$
Gain-Bandwidth Product*		f <sub>T</sub>	_	200	_	MHz	V <sub>CE</sub> = 10V, I <sub>E</sub> = -5mA, f = 100MHz

<sup>\*</sup> Transistor - For Reference Only



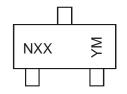


#### Ordering Information (Note 4 & 5)

Device	Packaging	Shipping
DDTD122LU-7-F	SOT-323	3000/Tape & Reel
DDTD142JU-7-F	SOT-323	3000/Tape & Reel
DDTD122TU-7-F	SOT-323	3000/Tape & Reel
DDTD142TU-7-F	SOT-323	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**



NXX = Product Type Marking Code See Page 1 Table YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	N	Р	R	S	Т	U	V	W	Х	Υ	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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